



M T B F

(E I A J R C R - 9 1 0 2)

Model	PBA600F-3R3
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	Re f e r e n c e
1	I C	Monolithic	9	0.2670	
2		Hybrid	0	0.0000	
3	Transistors		22	0.6203	
4	Diodes		54	1.1230	
5	LED•Optocouplers		7	0.4212	
6	Resistors		217	0.4183	
7	Capacitors		109	0.9901	
8	Transformer•Choke Coil		33	0.8800	
9	Connectors		1193	0.6708	
10	Others		15	2.9410	
Total Failure Rate [10 ⁻⁶ /H]				8.3317	

M T B F	[H]	121,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—